Diode Module

STARPOWER

SEMICONDUCTOR

FRED

FD300CCH60C1S

Molding Type Module

600V/300A 2 in one-package



General Description

STARPOWER Diode Power Module provides low forward voltage as well as low reverse recovery loss. They are designed for the applications such as SMPS.

Features

- Fast soft diode
- Low forward voltage drop
- Small temperature coefficient
- Low reverse recovery losses
- High ruggedness
- Low inductance
- Isolated copper baseplate using DBC technology

Typical Applications

- SMPS
- PFC
- Electric welders
- DC choppers

Symbol	Description	FD300CCH60C1S	Unit
V _{RRM}	Repetitive Peak Reverse Voltage	600	V
I _F	Continuous Forward Current	300	А
I _{FRM}	Repetitive Peak Forward Current	600	Α
P _D	Maximum Power Dissipation @ T _j =150°C	598	W
T _{jmax}	Maximum Junction Temperature	150	°C
T _{jop}	Operating Junction Temperature	-40 to +125	°C
T _{STG}	Storage Temperature Range	-40 to +125	°C
V _{ISO}	Isolation Voltage RMS,f=50Hz,t=1min	4000	V
М	Terminal Connection Torque, Screw M5	2.5 to 5.0	N.m
	Mounting Torque, Screw M6	3.0 to 5.0	IN.III
G	Weight of Module	150	g

Absolute Maximum Ratings $T_C=25$ °C unless otherwise noted

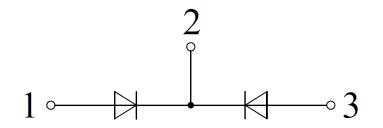
Electrical Characteristics of Diode $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
$V_{\rm F}$	Diode Forward	I _F =300A	T _j =25℃		1.40	1.80	v
	Voltage		Tj=125℃		1.45		
I _R	Diode Reverse	V _R =V _{RRM}	$T_j=25^{\circ}C$			1.0	mA
	Current					1.0	
Qr	Recovered	I _F =300A V _R =300V di/dt=-5500A/μs	T _i =25℃		16.4		μC
	Charge		Tj=125℃		22.0		
I _{RM}	Peak Reverse		T _j =25℃		205		Α
	Recovery Current		T _i =125℃		265		
E _{rec}	Reverse Recovery		T _i =25℃		2.66		mI
	Energy		T _i =125℃		5.12		mJ
L _{CE}	Stray Inductance					30	nH
R _{CC'+EE'}	Module Lead						
	Resistance,	$T_C=25$ °C		0.75		mΩ	
	Terminal To Chip						

Thermal Characteristics

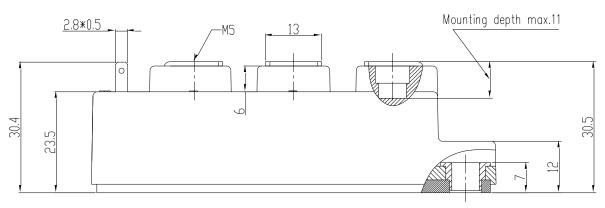
Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}$	Junction-to-Case (per Diode)		0.209	K/W
$R_{\theta CS}$	Case-to-Sink (Conductive grease applied)	0.05		K/W

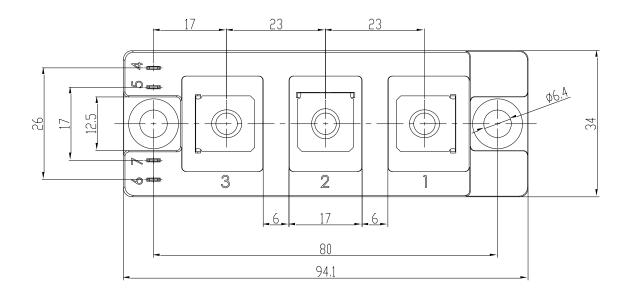
Equivalent Circuit Schematic



Package Dimensions

Dimensions in Millimeters





©2015 STARPOWER Semiconductor Ltd. 5/28/2015

3/4

Terms and Conditions of Usage

The data contained in this product datasheet is exclusively intended for technically trained staff. you and your technical departments will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to such application.

This product data sheet is describing the characteristics of this product for which a warranty is granted. Any such warranty is granted exclusively pursuant the terms and conditions of the supply agreement. There will be no guarantee of any kind for the product and its characteristics.

Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of our product, please contact the sales office, which is responsible for you (see <u>www.powersemi.cc</u>), For those that are specifically interested we may provide application notes.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact the sales office, which is responsible for you.

Should you intend to use the Product in aviation applications, in health or live endangering or life support applications, please notify.

If and to the extent necessary, please forward equivalent notices to your customers. Changes of this product data sheet are reserved.